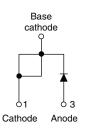


**Vishay Semiconductors** 

# Schottky Rectifier, 20 A





PRODUCT SUMMARY	ſ
Package	TO-220AC
I <sub>F(AV)</sub>	20 A
V <sub>R</sub>	15 V
$V_F$ at $I_F$	See Electrical table
I <sub>RM</sub> max.	600 mA at 100 °C
T <sub>J</sub> max.	125 °C
Diode variation	Single die
E <sub>AS</sub>	10 mJ

## FEATURES

- 125 °C T<sub>J</sub> operation ( $V_R < 5 V$ )
- Optimized for OR-ing applications
- Ultra low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified according to JEDEC-JESD47
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)

### DESCRIPTION

The Schottky rectifier module has been optimized for ultra low forward voltage drop specifically for the OR-ing of parallel power supplies. The proprietary barrier technology allows for reliable operation up to 125 °C junction temperature. Typical applications are in parallel switching power supplies, converters, reverse battery protection, and redundant power subsystems.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS	VALUES	UNITS						
I <sub>F(AV)</sub>	Rectangular waveform	20	A						
V <sub>RRM</sub>		15	V						
I <sub>FSM</sub>	t <sub>p</sub> = 5 μ <mark>s sine</mark>	700	А						
V <sub>F</sub>	19 A <sub>pk</sub> , T <sub>J</sub> = 125 °C (typical)	0.25	V						
TJ	Range	- 55 to 125	°C						

VOLTAGE RATINGS				
PARAMETER	SYMBOL	VS-STPS20L15DPbF	VS-STPS20L15D-N3	UNITS
Maximum DC reverse voltage	V <sub>R</sub>	15	15	V
Maximum working peak reverse voltage	V <sub>RWM</sub>	15	15	v

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST CONE	VALUES	UNITS					
Maximum average forward current See fig. 5	I <sub>F(AV)</sub>	50 % duty cycle, $T_C = 85 \ ^\circ C$ , r	20	A					
Maximum peak one cycle non-repetitive surge current		5 $\mu s$ sine or 3 $\mu s$ rect. pulse	Following any rated load condition and with rated	700	A				
See fig. 7	IFSM	10 ms sine or 6 ms rect. pulse	V <sub>RRM</sub> applied	330					
Non-repetitive avalanche energy	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 2 A, L = 6 mH	10	mJ					
Repetitive avalanche current	I <sub>AR</sub>		Current decaying linearly to zero in 1 $\mu$ s Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>B</sub> typical						

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RoHS

COMPLIANT

HALOGEN

FREE



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ELECTRICAL SPECIFICATIONS										
PARAMETER	SYMBOL	TEST CC	TEST CONDITIONS							
		19 A	T <sub>.1</sub> = 25 °C	-	0.41					
Forward voltage drop See fig. 1	V <sub>FM</sub> <sup>(1)</sup>	40 A	1j=25 C	-	0.52	v				
	V FM ( )	19 A	T <sub>.1</sub> = 125 °C	0.25	0.33					
		40 A	$1_{\rm J} = 125$ C	0.37	0.50					
Reverse leakage current	I <sub>BM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	$V_{\rm B} = \text{Rated } V_{\rm B}$	-	10	mA				
See fig. 2	IRM (**	T <sub>J</sub> = 100 °C	$v_{\rm R} = haleu v_{\rm R}$	-	600	IIIA				
Threshold voltage	V <sub>F(TO)</sub>			0.182		V				
Forward slope resistance	r <sub>t</sub>	ij = ij maximum	$T_{J} = T_{J}$ maximum							
Maximum junction capacitance	CT	$V_{R} = 5 V_{DC}$ (test signal rar	-	2000	pF					
Typical series inductance	L <sub>S</sub>	Measured lead to lead 5	8	-	nH					
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>		10	000	V/µs				

#### Note

 $^{(1)}\,$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS					
Maximum junction temperature range	TJ		- 55 to 125	°C					
Maximum storage temperature range	T <sub>Stg</sub>		- 55 to 150						
Maximum thermal resistance, junction to case	R <sub>thJC</sub>	DC operation See fig. 4	1.5						
Typical thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, smooth and greased (for TO-220)	0.50	°C/W					
Maximum thermal resistance, junction to ambient	R <sub>thJA</sub>	DC operation (for D <sup>2</sup> PAK)	40						
Approvimate weight			2	g					
Approximate weight			0.07	oz.					
Mounting torque		Non-lubricated threads	6 (5)	kgf · cm					
Mounting torque maximum		Non-hubricateu trireaus	12 (10)	(lbf ⋅ in)					
Marking device		Case style TO-220AC	STPS2	0L15D					

2



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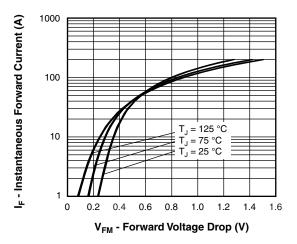


Fig. 1 - Maximum Forward Voltage Drop Characteristics

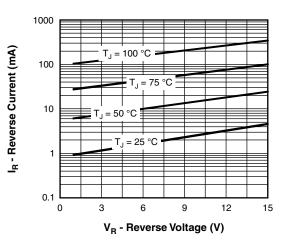


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

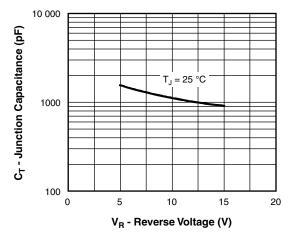
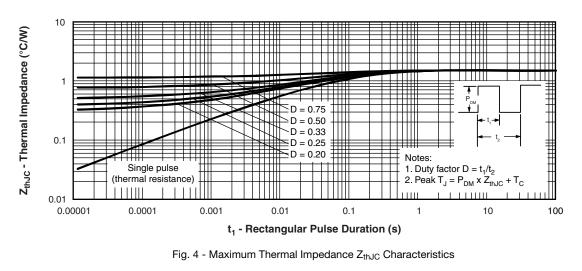


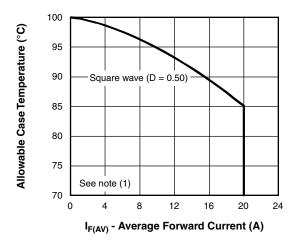
Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

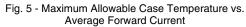


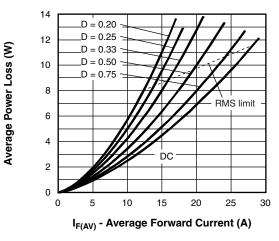
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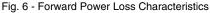


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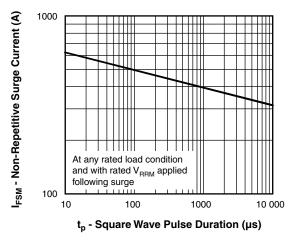


Fig. 7 - Maximum Non-Repetitive Surge Current

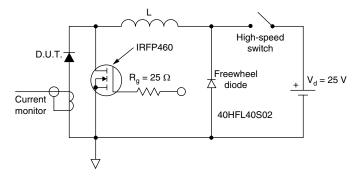


Fig. 8 - Unclamped Inductive Test Circuit

#### Note

<sup>(1)</sup> Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;

 $Pd_{REV}$  = Inverse power loss =  $V_{R1} \times I_R (1 - D)$ ;  $I_R$  at  $V_{R1}$  = 80 % rated  $V_R$ 

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Pd = Forward power loss =  $I_{F(AV)} \times V_{FM}$  at  $(I_{F(AV)}/D)$  (see fig. 6);



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### **ORDERING INFORMATION TABLE**

Device code	VS-	STPS	20	L	15	D	PbF		
	1	2	3	4	5	6	7		
	<ol> <li>Vishay Semiconductors product</li> <li>Schottky STPS series</li> <li>Current rating (20 = 20 A)</li> </ol>								
	4 - 5 - 6 -	Volta	age ratii	tage dro ng (15 = al part n	15 V)				
	7	• P	bF = Le	ntal digit ead (Pb)∘					

• -N3 = Halogen-free, RoHS compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-STPS20L15DPbF	50	1000	Antistatic plastic tube					
VS-STPS20L15D-N3	50	1000	Antistatic plastic tube					

LINKS TO RELATED DOCUMENTS							
Dimensions		www.vishay.com/doc?95221					
Part marking information	TO-220AC PbF	www.vishay.com/doc?95224					
	TO-220AC -N3	www.vishay.com/doc?95068					
SPICE model		www.vishay.com/doc?95305					



**Vishay Semiconductors** 

**TO-220AC** 

plane

### **DIMENSIONS** in millimeters and inches









**Diodes** 1 + 2 - Cathode 3 - Anode

Conforms to JEDEC outline TO-220AC

SYMBOL	MILLIM	IETERS	INC	HES	NOTES	SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STMBUL	MIN.	MAX.	MIN.	MAX.	NOTES	STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.25	4.65	0.167	0.183		E1	6.86	8.89	0.270	0.350	6
A1	1.14	1.40	0.045	0.055		E2	-	0.76	-	0.030	7
A2	2.56	2.92	0.101	0.115		е	2.41	2.67	0.095	0.105	
b	0.69	1.01	0.027	0.040		e1	4.88	5.28	0.192	0.208	
b1	0.38	0.97	0.015	0.038	4	H1	6.09	6.48	0.240	0.255	6, 7
b2	1.20	1.73	0.047	0.068		L	13.52	14.02	0.532	0.552	
b3	1.14	1.73	0.045	0.068	4	L1	3.32	3.82	0.131	0.150	2
с	0.36	0.61	0.014	0.024		L3	1.78	2.13	0.070	0.084	
c1	0.36	0.56	0.014	0.022	4	L4	0.76	1.27	0.030	0.050	2
D	14.85	15.25	0.585	0.600	3	ØР	3.54	3.73	0.139	0.147	
D1	8.38	9.02	0.330	0.355		Q	2.60	3.00	0.102	0.118	
D2	11.68	12.88	0.460	0.507	6	θ	90° t	o 93°	90° t	o 93°	
E	10.11	10.51	0.398	0.414	3, 6						

Notes

<sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994

- <sup>(2)</sup> Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- <sup>(4)</sup> Dimension b1, b3 and c1 apply to base metal only
- <sup>(5)</sup> Controlling dimension: inches
- <sup>(6)</sup> Thermal pad contour optional within dimensions E, H1, D2 and E1
- <sup>(7)</sup> Dimension E2 x H1 define a zone where stamping and singulation irregularities are allowed
- <sup>(8)</sup> Outline conforms to JEDEC TO-220, D2 (minimum) where dimensions are derived from the actual package outline



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